FAIRCHILD

SEMICONDUCTOR

74LCX16244 Low Voltage 16-Bit Buffer/Line Driver with 5V Tolerant Inputs and Outputs

General Description

The LCX16244 contains sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The LCX16244 is designed for low voltage (2.5 or 3.3V) $\rm V_{CC}$ applications with capability of interfacing to a 5V signal environment.

The LCX16244 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V to 3.6V V_{CC} specifications provided
- 4.5 ns t_{PD} max, 10 µA I_{CCQ} max
- Power down high impedance inputs and outputs

February 1994

Revised June 2002

- Supports live insertion/withdrawal (Note 1)
- ± 24 mA output drive (V_{CC} = 3.0V)
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
 - Human body model > 2000V
 - Machine model > 200V
- Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA)

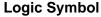
Note 1: To ensure the high-impedance state during power up or down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

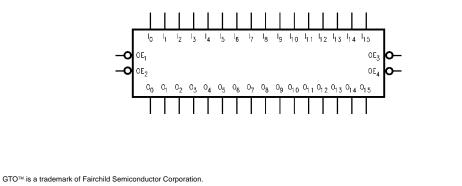
Ordering Code:

Order Number	Package Number	Package Description
74LCX16244G (Note 2)(Note 3)	BGA54A	54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide
74LCX16244MEA (Note 3)	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16244MTD (Note 3)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Note 2: Ordering code "G" indicates Trays.

Note 3: Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.





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74LCX16244

Connection Diagrams

Pin

Assignm	ent for SSO	Рa	nd TSSOP
οe,		48	- OE2
o ₀ —	2	47	- I ₀
0 ₁ —	3	46	— ų
GND -	4	45	— GND
0 ₂ —	5	44	- 1 ₂
0 ₃ —	6	43	- I ₃
v _{cc} —	7	42	— v _{cc}
0 ₄ —	8	41	— I ₄
0 ₅ —	9	40	— I ₅
GND —	10	39	— GND
0 ₆ —	11	38	— 1 ₆
0 ₇ —	12	37	— 1 ₇
0 ₈ —	13	36	— 1 ₈
0 ₉ —	14	35	— I ₉
GND —	15	34	— GND
0 ₁₀ —	16	33	— 4 o
0 ₁₁ —	17	32	— 4 ₁
v _{cc} —	18	31	— v _{cc}
0 ₁₂ —	19	30	— I _{1 2}
0 ₁₃ —	20	29	— I _{1 3}
GND —	21	28	— GND
0 ₁₄ —	22	27	— I _{1 4}
0 ₁₅ —	23	26	— I ₁₅
ŌĒ ₄ —	24	25	- OE3

Pin Assignment for FBGA

	1	2	3	4	5	6
A	0	0	0	0	0	0
В	0	0	0	0	0	0
С	0	0	0	0	0	0
Δ	0	0	0	0	0	0
ш	0	0	0	0	0	0
ш	0	Ο	0	0	0	0
G	0	0	0	0	0	0
н	0	0	0	0	0	0
ſ	0	0	0	0	0	0

(Top Thru View)

Pin Descriptions

Pin Names	Description
OEn	Output Enable Input (Active LOW)
I ₀ —I ₁₅	Inputs
I ₀ -I ₁₅ O ₀ -O ₁₅ NC	Outputs
NC	No Connect

FBGA Pin Assignments

	1	2	3	4	5	6
Α	O ₀	NC	OE ₁	OE ₂	NC	I ₀
В	0 ₂	0 ₁	NC	NC	I ₁	l ₂
С	O ₄	O ₃	V _{CC}	V _{CC}	I ₃	I ₄
D	0 ₆	0 ₅	GND	GND	۱ ₅	I ₆
E	0 ₈	0 ₇	GND	GND	۱ ₇	I ₈
F	O ₁₀	O ₉	GND	GND	l ₉	I ₁₀
G	0 ₁₂	0 ₁₁	V _{CC}	V _{CC}	I ₁₁	I ₁₂
н	O ₁₄	O ₁₃	NC	NC	I ₁₃	I ₁₄
J	0 ₁₅	NC	\overline{OE}_4	\overline{OE}_3	NC	I ₁₅

Truth Tables

li	nputs	Outputs
OE ₁	I ₀ –I ₃	0 ₀ –0 ₃
L	L	L
L	Н	Н
Н	Х	Z
li	nputs	Outputs
OE ₂	I ₄ –I ₇	0 ₄ –0 ₇
L	L	L
L	Н	Н
Н	Х	Z
li	nputs	Outputs
OE ₃	I ₈ –I ₁₁	0 ₈ –0 ₁₁
L	L	L
L	Н	Н
Н	Х	Z
li	nputs	Outputs
OE ₄	I ₁₂ –I ₁₅	0 ₁₂ -0 ₁₅
L	L	L
L	Н	Н
Н	Х	Z
H = HIGH Voltage Lev	vel	•

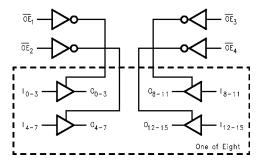
L = LOW Voltage Level X = Immaterial Z = High Impedance

Functional Description

The LCX16244 contains sixteen non-inverting buffers with 3-STATE standard outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. The 3-STATE outputs are controlled by an Output Enable (\overline{OE}_n) input for each nibble. When \overline{OE}_n is LOW, the outputs are in 2-state mode. When \overline{OE}_n is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

74LCX16244

Logic Diagram



74LCX16244

Absolute Maximum Ratings(Note 4)

Symbol	Parameter	Value	Conditions	Units
V _{CC}	Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	-0.5 to +7.0		V
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V
		-0.5 to $V_{CC} + 0.5$	Output in HIGH or LOW State (Note 5)	v
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA
I _{OK}	DC Output Diode Current	-50	V _O < GND	mA
		+50	$V_{O} > V_{CC}$	IIIA
lo	DC Output Source/Sink Current	±50		mA
I _{CC}	DC Supply Current per Supply Pin	±100		mA
I _{GND}	DC Ground Current per Ground Pin	±100		mA
T _{STG}	Storage Temperature	-65 to +150		°C

Recommended Operating Conditions (Note 6)

Symbol	Parameter		Min	Max	Units
V _{CC}	Supply Voltage	2.0	3.6	V	
		Data Retention	1.5	3.6	v
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V
		3-STATE	0	5.5	v
I _{OH} /I _{OL}	Output Current	$V_{CC} = 3.0V - 3.6V$		±24	
		$V_{CC} = 3.0V - 3.6V$ $V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$		±12	mA
		$V_{CC}=2.3V-2.7V$		±8	
T _A	Free-Air Operating Temperature		-40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, $V_{IN} = 0.8V-2.0V$, $V_{CC} = 3.0V$		0	10	ns/V

Note 4: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 5: I_O Absolute Maximum Rating must be observed.

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{CC}	$T_A = -40^{\circ}C$	Units	
-		Conditions	(V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 - 3.6	2.0		v
V _{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 - 3.6		0.8	v
√ _{ОН}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.3 - 3.6	V _{CC} - 0.2		
		I _{OH} = -8 mA	2.3	1.8		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
		I _{OH} = -18 mA	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 - 3.6		0.2	
		I _{OL} = 8 mA	2.3		0.6	
		$I_{OL} = 12 \text{ mA}$	2.7		0.4	V
		I _{OL} = 16 mA	3.0		0.4	
		I _{OL} = 24 mA	3.0		0.55	
h	Input Leakage Current	$0 \le V_I \le 5.5V$	2.3 - 3.6		±5.0	μA
oz	3-STATE Output Leakage	$0 \le V_O \le 5.5V$	2.3 - 3.6		±5.0	μA
		$V_I = V_{IH} \text{ or } V_{IL}$				μΑ
OFF	Power-Off Leakage Current	$V_1 \text{ or } V_0 = 5.5 V$	0		10	μA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V _{cc}	T _A = -40°0	Units	
		Conditiona	(V)	Min	Max	Unita
lcc	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 - 3.6		20	μA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 7)	2.3 - 3.6		±20	μΑ
Δl _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μΑ
Nets 7: Ou	territe disable disa 0.0TATE subs					

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

			$T_A = -40^{\circ}C$ to $+85^{\circ}C$, $R_L = 500 \Omega$					
Cumhal	Devenuerter	V _{CC} = 3.3	$3V \pm 0.3V$	V _{CC} =	= 2.7V	V _{CC} = 2	.5 ± 0.2V	Unite
Symbol	Parameter	C _L =	C _L = 50 pF		C _L = 50 pF		30 pF	Units
		Min	Max	Min	Max	Min	Max	-
t _{PHL}	Propagation Delay	1.0	4.5	1.0	5.2	1.0	5.4	
t _{PLH}	Data to Output	1.0	4.5	1.0	5.2	1.0	5.4	ns
t _{PZL}	Output Enable Time	1.0	5.5	1.0	6.3	1.0	7.2	20
t _{PZH}		1.0	5.5	1.0	6.3	1.0	7.2	ns
t _{PLZ}	Output Disable Time	1.0	5.4	1.0	5.7	1.0	6.5	20
t _{PHZ}		1.0	5.4	1.0	5.7	1.0	6.5	ns
t _{OSHL}	Output to Output Skew (Note 8)		1.0					
t _{OSLH}			1.0					ns

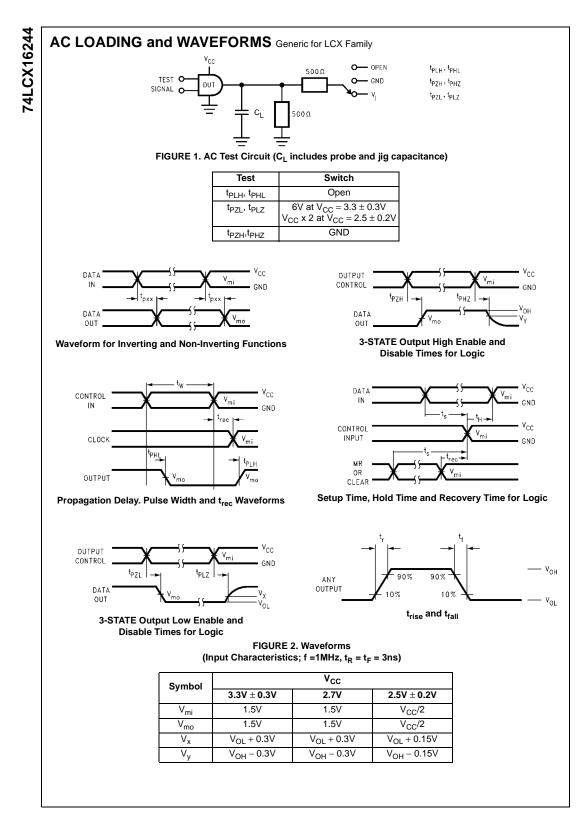
Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

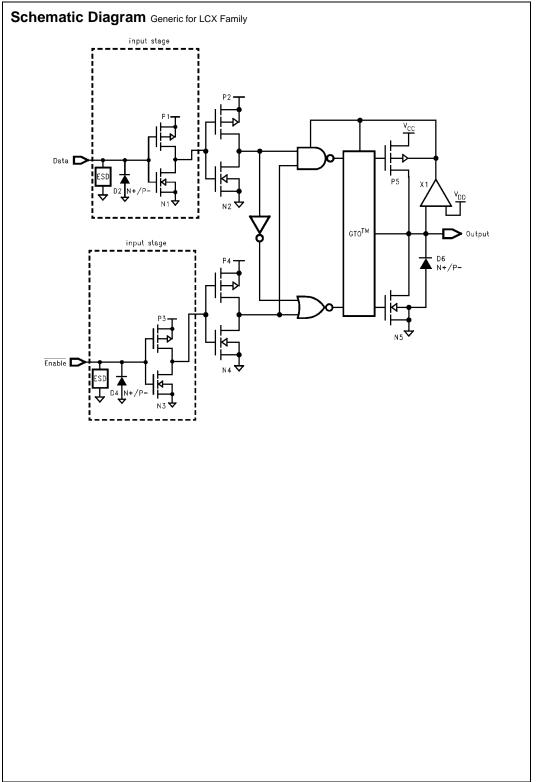
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = 25°C Typical	Unit
V _{OLP}	Quiet Output Dynamic Peak VOL	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.8	V
		$C_L=30pF,\ V_{IH}=2.5V,\ V_{IL}=0V$	2.5	0.6	v
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L = 30 p F, \ V_{IH} = 2.5 V, \ V_{IL} = 0 V$	2.5	-0.6	v

Capacitance

Symbol	Parameter	Conditions	Typical	Units
CIN	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10 MHz	20	pF





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